

# RD15LD74AP, RD15LD74ANP, RD15LD74AT

8-bit D-type Flip-Flop Driver (with Clear)

REJ03D0894-0300 Rev.3.00 Feb 29, 2008

# **Description**

RD15LD74AP, RD15LD74ANP, RD15LD74AT have eight D-type flip-flop drivers and high voltage NMOS output (open drain output) in a 20 pin package. Each bit, there are a common clear and clock input. The input signal is output with the rising edge of clock signals. The voltage of maximum 15 V can be impressed to the drain-source voltage.

### **Features**

• Application of amusement equipment.

• Output voltage :  $V_{DS}$  (max) = 15 V

• Output current :  $I_{DS}$  (max) = 200 mA (par pin)

• Supply voltage range: 3.0 to 5.5 V

• Operating temperature range : -20 to +85 °C

• Quiescent supply current : 5 μA max.

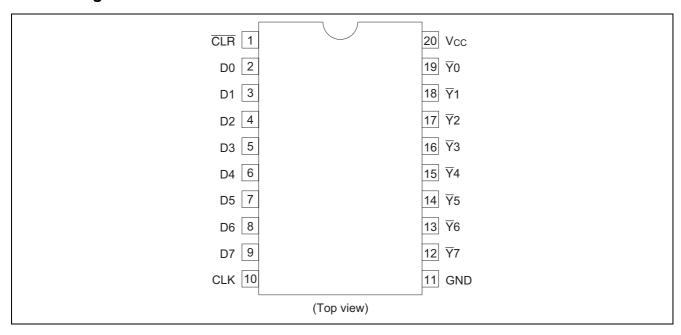
• Low input current : 1 μA max.

• Ordering Information

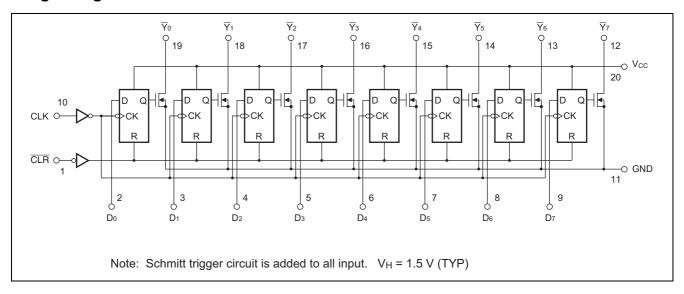
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Packing Abbreviation (Quantity)	Surface Treatment
RD15LD74APT0	SDIP-20 pin	PRDP0020BA-A (20P4B)	Р	T (1,125 pcs/box)	0 (Sn-Cu)
RD15LD74ANPT0	DILP-20 pin	PRDP0020AC-B (DP-20NEV)	Р	T (1,000 pcs/box)	0 (Ni/Pd/Au)
RD15LD74ATH0	TSSOP-20 pin	PTSP0020JB-A (TTP-20DAV)	Т	H (2,000 pcs/reel)	0 (Ni/Pd/Au)

Note: Please consult the sales office for the above package availability.

# **Pin Arrangement**



# **Logic Diagram**



# **Function Table**

	Output		
CLR	CLK	D	$\overline{Y}$
L	X	X	Z
Н	<b>↑</b>	L	Z
Н	<b>↑</b>	Н	L
Н	L	X	Y <sub>0</sub>
Н	<b>\</b>	X	Y <sub>0</sub>

H: High level

L : Low level

X : Immaterial

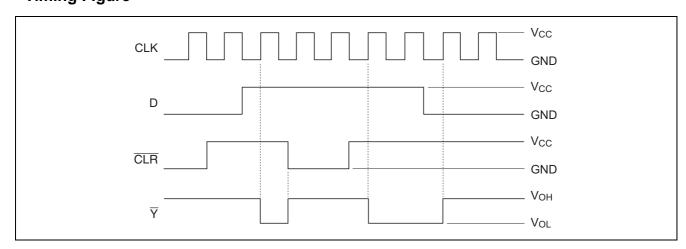
Z : High Impedance

 $\ensuremath{\uparrow}$  : Low to High transition

↓ : High to Low transition

 $Y_0$ : Level of  $\overline{Y}$  before the indicated steady input conditions were established.

# **Timing Figure**



# **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit		Conditions
Supply voltage	$V_{CC}$	6.5	V		
Input voltage	VI	$-0.5$ to $V_{CC}$	V		
Output voltage	$V_{DS}$	-0.5 to 15	V	Output: "Z" (off)	
Output current	I <sub>DS</sub>	200	mA	Output: "on", Current of one circuit	
Maximumana		1.47		SDIP	Ta = 25°C
Maximum power dissipation *1	P <sub>T</sub>	1.38	W	DILP	Base implementation
uissipation		0.76		TSSOP	base implementation
Storage temperature	Tstg	-55 to +125	°C		

Note: The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

# **Recommended Operating Conditions**

Item	Symbol	Ratings		Unit		Conditions
Supply voltage	$V_{CC}$	3.0	5.5	V		
Input voltage	Vı	0	V <sub>CC</sub>	V		
Output voltage	$V_{DS}$	0	15	V	Output "Z"	(off)
	I <sub>DS</sub>	0	200	mA	SDIP	Duty cycle ≤ 60%
Output current		0	150		SDIF	Duty cycle ≤ 100%
(Current of an one circuit,		0	200	mA	DILP	Duty cycle ≤ 55%
when eight circuit		0	140			Duty cycle ≤ 100%
operation)		0	200	mA	TSSOP	Duty cycle ≤ 25%
		0	105		13306	Duty cycle ≤ 100%
Input rise / fall time	t <sub>r</sub> , t <sub>f</sub>	0	500	ns	V <sub>CC</sub> = 3.0 V, 4.5 V	
Operating temperature	Та	-20	85	°C		

Note: Unused or floating inputs must be held high or low.

# **Electrical Characteristics**

 $(Ta = -20 \text{ to } +85^{\circ}C)$ 

Item	Symbol	VCC (V)	Ratings			Unit	Conditions	
item		VCC (V)	Min	Тур	Max	Onit	Conditions	
	V <sub>IH</sub>	3.0 to 3.6	V <sub>CC</sub> ×0.84		_	V		
Input voltage	VIH	4.5 to 5.5	V <sub>CC</sub> ×0.76		_	V		
input voitage	VIL	3.0 to 3.6	_		V <sub>CC</sub> ×0.16	>		
	V IL	4.5 to 5.5	_		V <sub>CC</sub> ×0.24			
		3.0 to 3.6	_	0.30	0.45		I <sub>DS</sub> = 100 mA	
Outrout valtage	V <sub>DS</sub>	4.5 to 5.5	_	0.25	0.38	V	IDS = TOO IIIA	
Output voltage		3.0 to 3.6	_	0.60	0.90		I <sub>DS</sub> = 200 mA	
		4.5 to 5.5	_	0.51	0.77			
"H" input current	I <sub>IH</sub>	3.0 to 5.5	_	0.005	1.0	μΑ	$V_I = V_{CC}$	
"L" input current	I <sub>IL</sub>	3.0 to 5.5	_	0.005	-1.0	μΑ	$V_I = 0 V$	
Quiocoont cumply	Icc	5.5		0.005 5.0	5.0		All output "Z" (off)	
Quiescent supply current		5.5	_		μΑ	$V_I = V_{CC}$ or GND		
		5.5	_	0.005	5.0		All output "on", $V_I = V_{CC}$ or GND	
Output off state	I <sub>DS</sub>	5.0		0.002	5.0	μА	V <sub>DS</sub> = 12 V	
leak current	.00	0.0		0.002	0.0	μ/ (	100 - 12	
Output on resister	R <sub>DS</sub>	4.5	_	2.5	3.8	Ω	I <sub>DS</sub> = 100 mA	

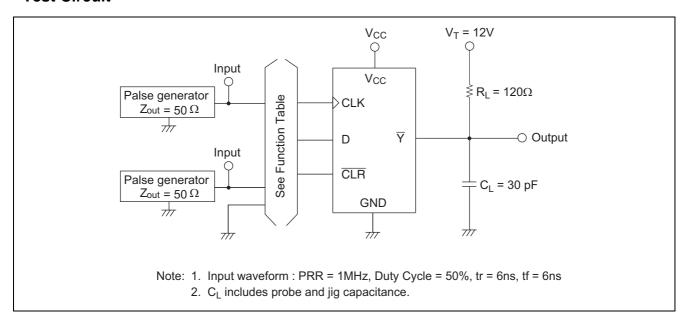
<sup>1.</sup> The maximum package power dissipation was calculated using a junction temperature of 150°C

# **Switching Characteristics**

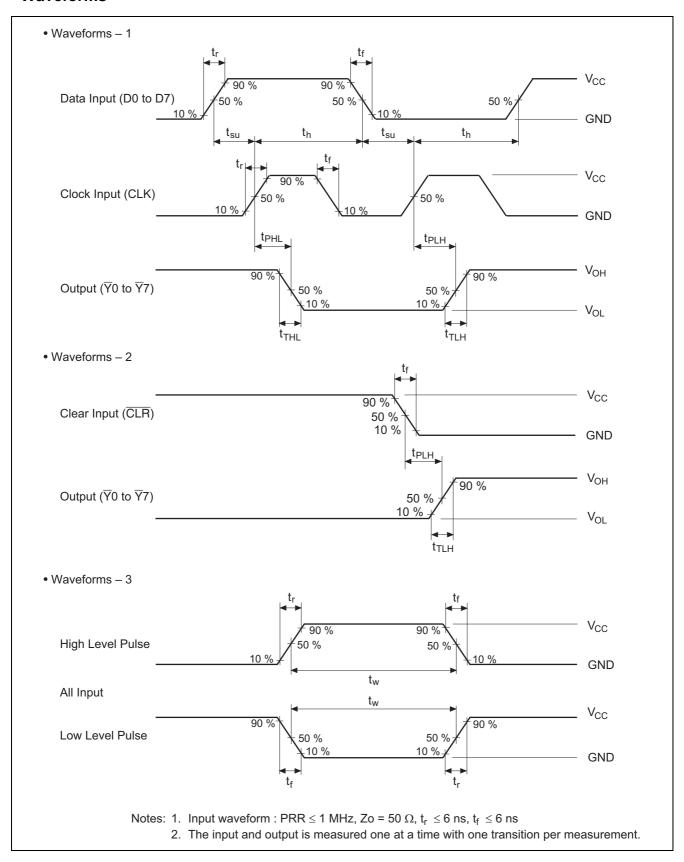
 $(Ta = -20 \text{ to } +85^{\circ}\text{C}, CL = 30 \text{ pF}, tr = tf = 6 \text{ ns})$ 

Item	Symbol	VCC (V) Ratings		Unit	Conditions		
item	Syllibol	VCC (V)	Min	Max	Unit	Conditions	
Maximum clock	f <sub>max</sub>	$3.3 \pm 0.3$		15	MHz		
frequency	ımax	$5.0\pm0.5$	_	20	IVII IZ		
Propagation delay	t	$3.3\pm0.3$	1.0	65	ns	CLK, $\overline{\text{CLR}}$ to $\overline{\text{Y}}$	
time	t <sub>PLH</sub>	$5.0\pm0.5$	1.0	50	115	CLN, CLN to 1	
Propagation delay	<b>t</b>	$3.3 \pm 0.3$	1.0	60	ns	CLK to $\overline{Y}$	
time	t <sub>PHL</sub>	$5.0 \pm 0.5$	1.0	45	115	CLN 10 Y	
Setup time	t <sub>su</sub>	$3.3 \pm 0.3$	25	_	ns	D to CLK	
Setup time		$5.0 \pm 0.5$	20	_	115	D to CLN	
Hold time	t <sub>h</sub>	$3.3 \pm 0.3$	3	_	ns	CLK to D	
i ioid time		$5.0 \pm 0.5$	3	_	115	CLK 10 D	
Pulse width	t <sub>W</sub>	$3.3\pm0.3$	50	_	ns	CLK, CLR	
Puise width		$5.0 \pm 0.5$	40	_	115		
Output rise time	t <sub>TLH</sub>	$3.3 \pm 0.3$	_	30	ns	Ÿ	
		$5.0 \pm 0.5$	_	20	TIS	'	
Output fall time	e t <sub>THL</sub>	$3.3 \pm 0.3$	_	10	ns	Ÿ	
		$5.0 \pm 0.5$	_	5	115	T	

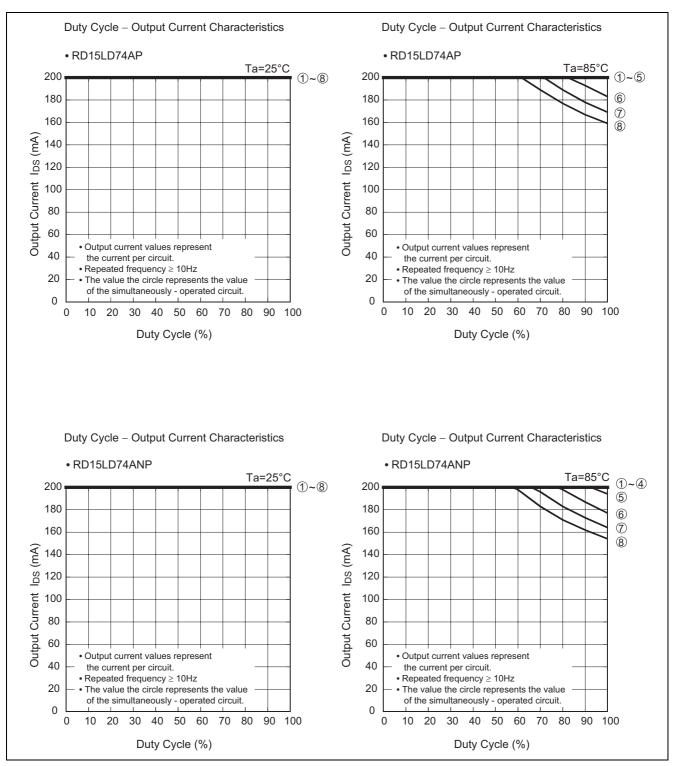
# **Test Circuit**



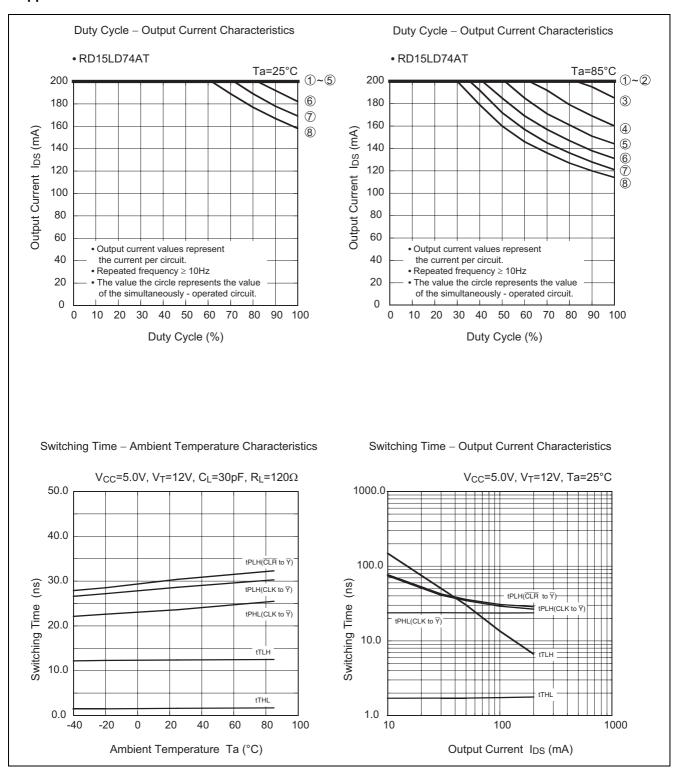
# **Waveforms**



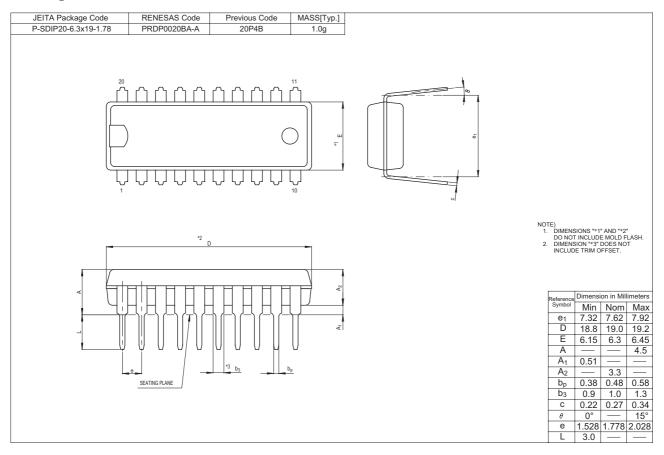
### **Application Data**

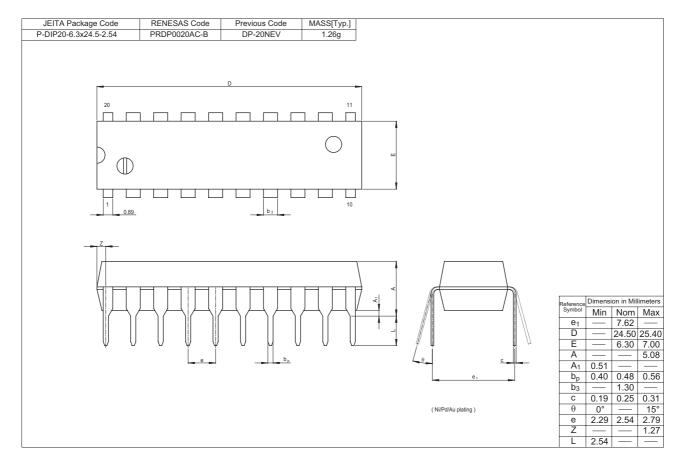


### **Application Data**

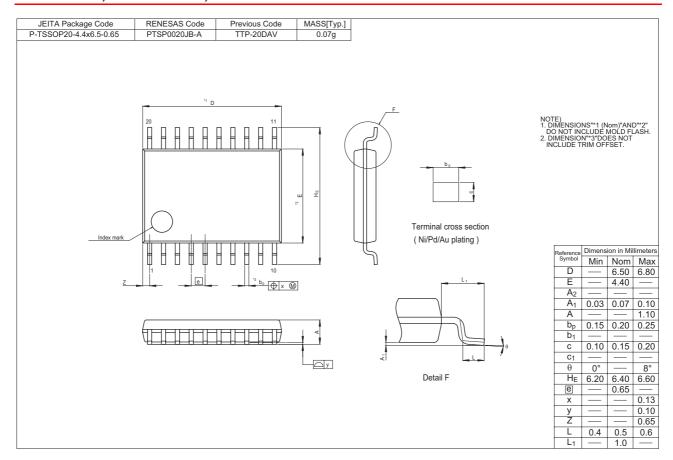


# **Package Dimensions**





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Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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### Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

**Renesas Technology Taiwan Co., Ltd.** 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
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Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510